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Fairchild Semiconductor FDPF085N10A

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November 2013

FDPF085N10A

N-Channel PowerTrench[®] MOSFET 100 V, 40 A, 8.5 m Ω

Features

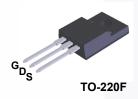
- $R_{DS(on)}$ = 6.5 m Ω (Typ.) @ V_{GS} = 10 V, I_D = 40 A
- · Fast Switching Speed
- Low Gate Charge, Q_G = 31 nC (Typ.)
- High Performance Trench Technology for Extremely Low $R_{\ensuremath{\mathsf{DS}}(\ensuremath{\mathsf{on}})}$
- · High Power and Current Handling Capability
- · RoHS Compliant

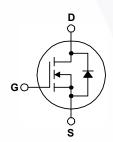
Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench[®] process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

Applications

- · Consumer Appliances
- LED TV
- Synchronous Rectification for ATX / Sever / Telecom PSU
- · Motor Drives and Uninterruptible Power Supplies
- · Micro Solar Inverter





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol		Parameter			Unit
V _{DSS}	Drain to Source Voltage			100	V
V _{GSS}	Gate to Source Voltage		/	±20	V
	Drain Current	- Continuous (T _C = 25°C)		40	А
^I D	Diam Current	- Continuous (T _C = 100°C)		28	
I _{DM}	Drain Current	- Pulsed	(Note 1)	160	Α
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		(Note 2)	269	mJ
dv/dt	Peak Diode Recovery dv/dt	Peak Diode Recovery dv/dt (Note 3)		6.0	V/ns
D	Power Dissipation	(T _C = 25°C)		33.3	W
P_{D}	- Derate Above 25°C			0.22	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +175	°C
T _L	Maximum Lead Temperature for	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			°C

Thermal Characteristics

Symbol	Parameter FDPF085N10A		Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max. 4.5		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max. 62.5		- 0/00



Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDPF085N10A	FDPF085N10A	TO-220F	Tube	N/A	N/A	50 units

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu\text{A}, V_{GS} = 0 \text{V}$	100	-	-	V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I_D = 250 μ A, Referenced to 25°C	-	0.07	-	V/°C
1	Zero Gate Voltage Drain Current	V _{DS} = 80 V, V _{GS} = 0 V	-	-	1	μА
I _{DSS} Zero Gate voltage Drain Current	$V_{DS} = 80 \text{ V}, T_{C} = 150^{\circ}\text{C}$	-	-	500	μΑ	
I _{GSS}	Gate to Body Leakage Current	V _{GS} = ±20 V, V _{DS} = 0 V	-	-	±100	nA

On Characteristics

$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2.0	-	4.0	V
R _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 96 A	-	6.5	8.5	mΩ
9 _{FS}	Forward Transconductance	V _{DS} = 10 V, I _D = 96 A	-	76	-	S

Dynamic Characteristics

C _{iss}	Input Capacitance	V - 50 V V - 0 V		-	2025	2695	pF
C _{oss}	Output Capacitance	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V},$ $f = 1 \text{ MHz}$	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V},$		468	620	pF
C _{rss}	Reverse Transfer Capacitance	1 - 1 101112		-\	20	-	pF
C _{oss} (er)	Engry Related Output Capacitance	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V}$		- \	752	-	pF
Q _{g(tot)}	Total Gate Charge at 10V			- \	31	40	nC
Q_{gs}	Gate to Source Gate Charge	$V_{GS} = 10 \text{ V}, V_{DS} = 50 \text{ V},$		-	9.7	-	nC
Q _{gs2}	Gate Charge Threshoid to Plateau	I _D = 96 A		-	5.0	-	nC
Q_{gd}	Gate to Drain "Miller" Charge		(Note 4)	-	7.5	-	nC
ESR	Equivalent Series Resistance (G-S)	f = 1 MHz		-	0.97	-	Ω

Switching Characteristics

t _{d(on)}	Turn-On Delay Time		-	18	46	ns
t _r		$V_{DD} = 50 \text{ V}, I_{D} = 96 \text{ A},$	-/	22	54	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, R_G = 4.7 \Omega$	-	29	68	ns
t _f	Turn-Off Fall Time	(Note 4)	_	8	26	ns

Drain-Source Diode Characteristics

Is	Maximum Continuous Drain to Source Diode Forward Current		-	-	40	Α
I _{SM}	Maximum Pulsed Drain to Source Diode Forward Current		-	-	160	Α
V_{SD}	Drain to Source Diode Forward Voltage V _{GS} = 0 V, I _{SD} = 96 A		-	-	1.3	V
t _{rr}	Reverse Recovery Time	$V_{DD} = 50 \text{ V}, V_{GS} = 0 \text{ V}, I_{SD} = 96 \text{ A},$	-	59	-	ns
Q _{rr}	Reverse Recovery Charge $dI_F/dt = 100 \text{ A/}\mu\text{s}$		-	80	-	nC

Notes:

- 1. Repetitive rating: pulse-width limited by maximum junction temperature.
- 2. L = 3 mH, I_{AS} = 13.4 A, R_G = 25 Ω , starting T_J = 25°C.
- 3. I $_{SD}$ \leq 40 A, di/dt \leq 200 A/ μ s, V $_{DD}$ \leq BV $_{DSS}$, starting T $_{J}$ = 25°C.
- 4. Essentially independent of operating temperature typical characteristics.



Typical Performance Characteristics

Figure 1. On-Region Characteristics

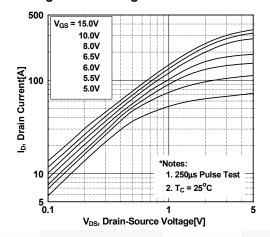


Figure 3. On-Resistance Variation vs. **Drain Current and Gate Voltage**

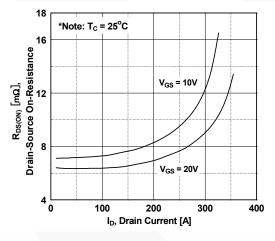


Figure 5. Capacitance Characteristics

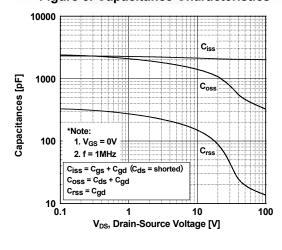


Figure 2. Transfer Characteristics

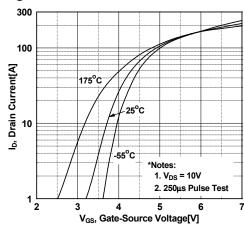


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

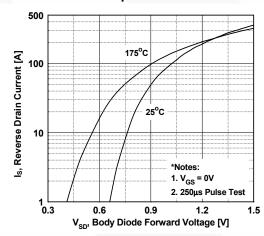
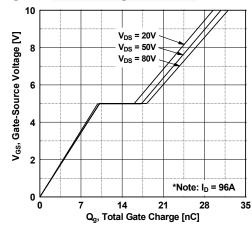


Figure 6. Gate Charge Characteristics





Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

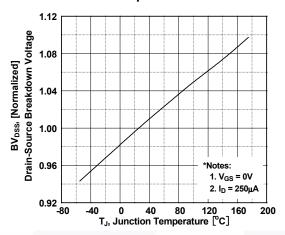


Figure 9. Maximum Safe Operating Area

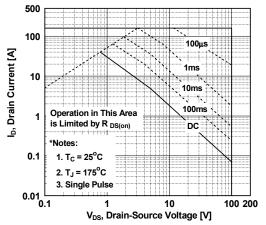


Figure 11. Eoss vs. Drain to Source Voltage

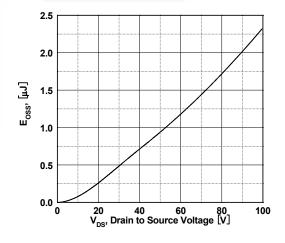


Figure 8. On-Resistance Variation vs. Temperature

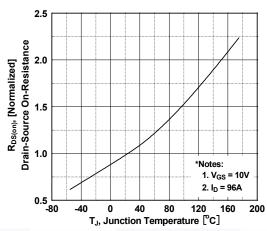


Figure 10. Maximum Drain Current vs. Case Temperature

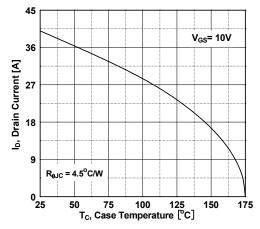
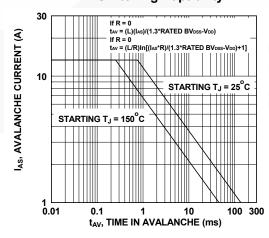


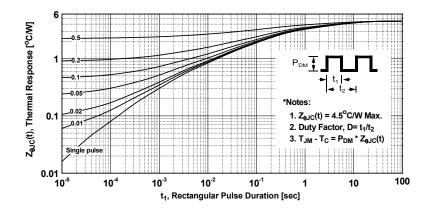
Figure 12. Unclamped Inductive Switching Capability





Typical Performance Characteristics (Continued)

Figure 13. Transient Thermal Response Curve





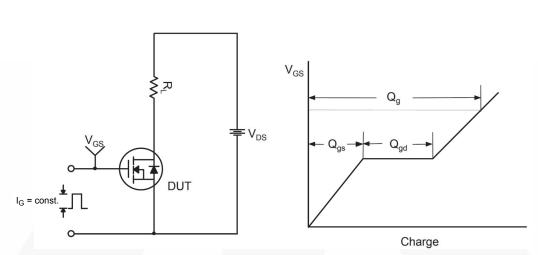


Figure 14. Gate Charge Test Circuit & Waveform

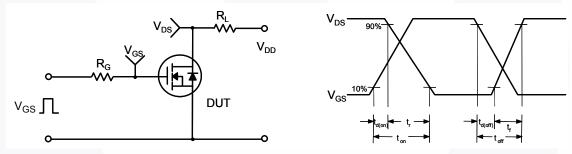


Figure 15. Resistive Switching Test Circuit & Waveforms

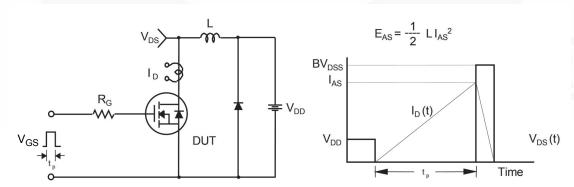


Figure 16. Unclamped Inductive Switching Test Circuit & Waveforms



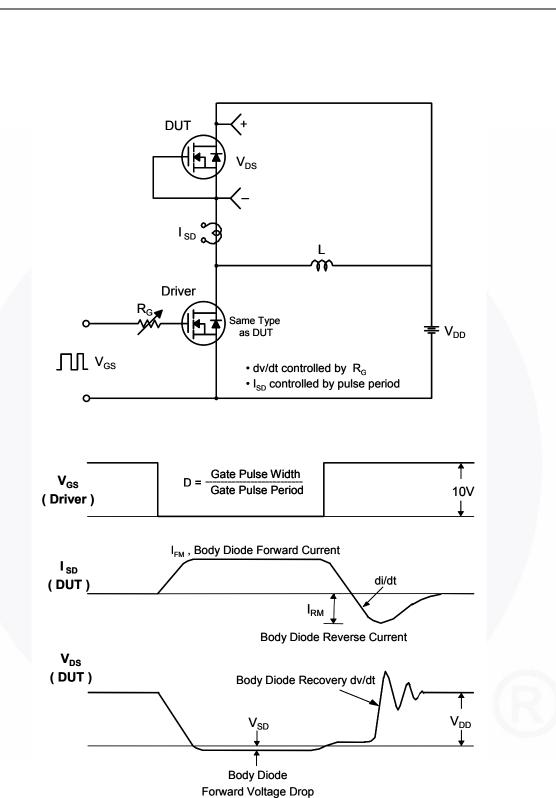


Figure 17. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

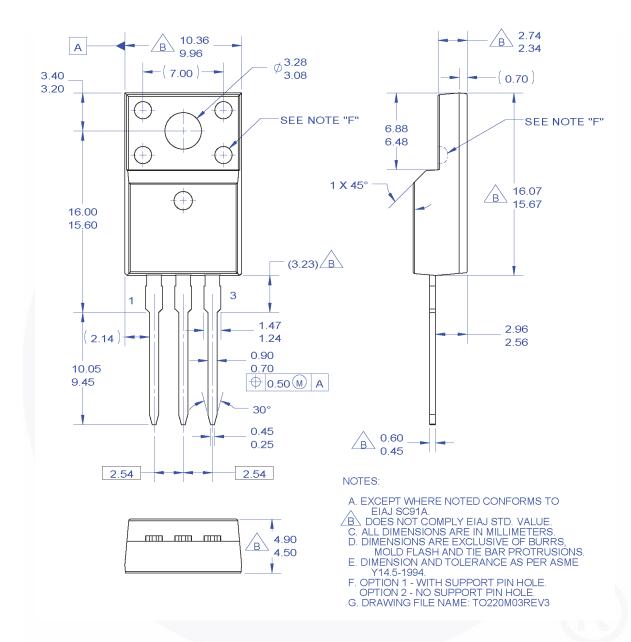


Figure 18. TO220, Molded, 3-Lead, Full Pack, EIAJ SC91, Straight Lead

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